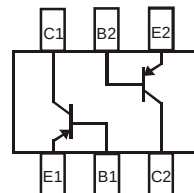


Features

- Epitaxial Planar Die Construction
- Small Surface Mount Package
- **Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed Over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.016 grams (approximate)


SOT-26


Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Continuous Collector Current	I _C	-500	mA

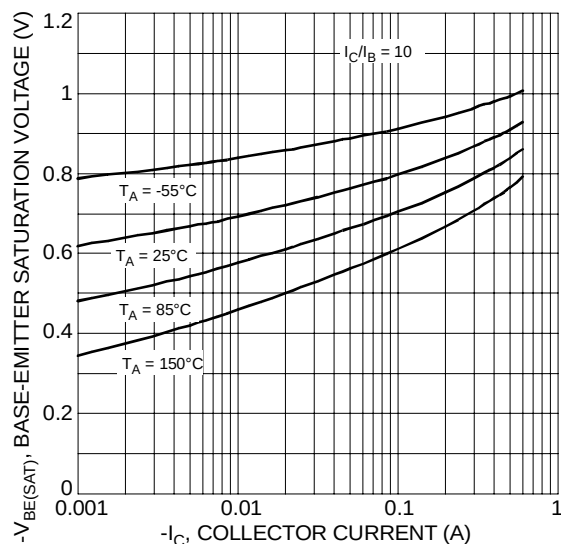
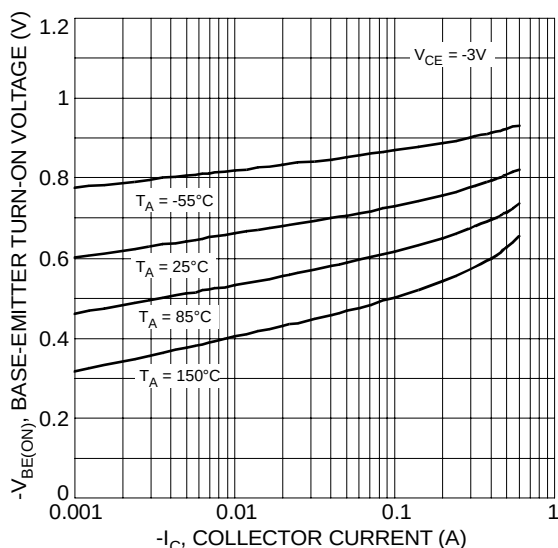
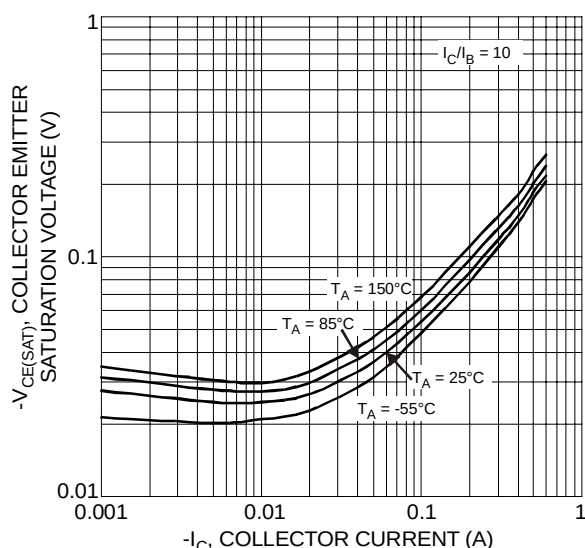
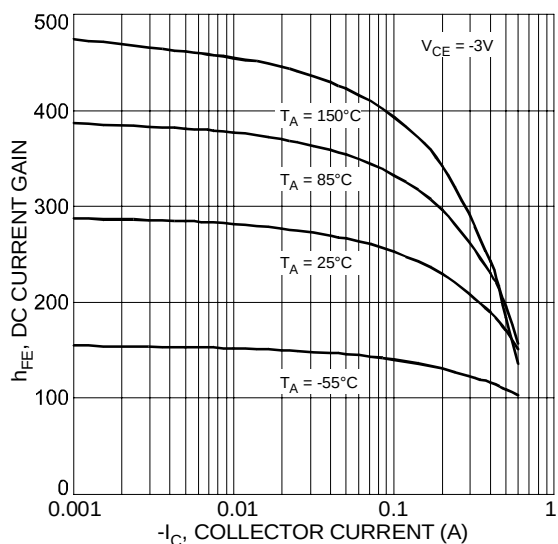
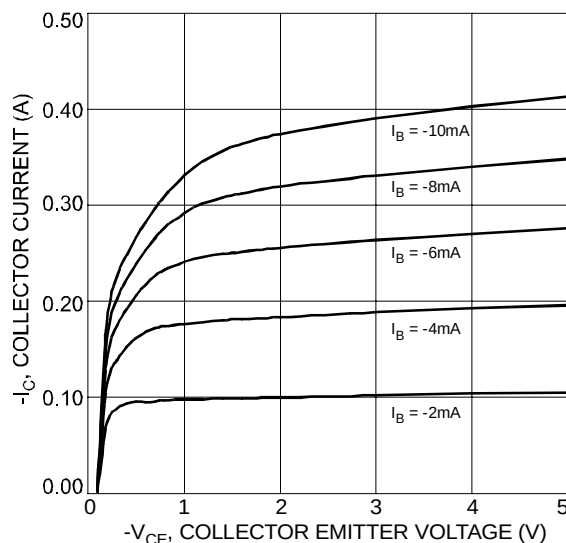
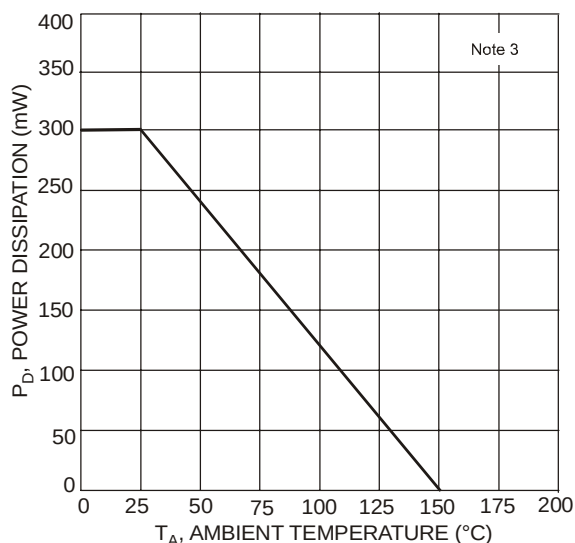
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @T _A = 25°C	P _D	300	mW
Thermal Resistance, Junction to Ambient Air (Note 3) @T _A = 25°C	R _{θJA}	417	°C /W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

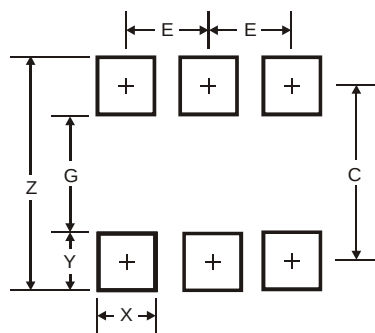
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-60	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-50	—	—	V	I _C = -1.0mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	—	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	—	—	-0.1	μA	V _{CB} = -30V
Emitter Cutoff Current	I _{EBO}	—	—	-0.1	μA	V _{EB} = -4.0V
ON CHARACTERISTICS (Note 4)						
DC Current Gain	h _{FE}	120	—	390	—	V _{CE} = -3.0V, I _C = -100mA
Collector-Emitter Saturation Voltage (Note 3)	V _{CE(SAT)}	—	—	-0.6	V	I _C = -500mA, I _B = -50mA
SMALL SIGNAL CHARACTERISTICS						
Gain Bandwidth Product	f _T	—	200	—	MHz	V _{CE} = -5V, I _E = 20mA, f = 100MHz
Output Capacitance	C _{ob}	—	7	—	pF	V _{CB} = -10V, I _E = 0, f = 1MHz

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on page 4 or on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Short duration pulse test used to minimize self-heating effect.



Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C	2.40
E	0.95

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